NSN 5961-00-105-8133

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-105-8133 **Inclosure Material:** Ceramic and metal **Overall Length:** 1.250 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 2.8 millimeters **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 reverse voltage, peak **Current Rating Per Characteristic:** 40.00 amperes average forward current averaged over a full 60-hz cycle **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Thread Series Designator:** Iso m **Terminal Type And Quantity:** 1 insulated wire lead w/terminal lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure:** Demilitarization:

Yes - demil/mli

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